

L Number	Hits	Search Text	DB	Time stamp
1	16024	ESD (electrostatic near discharge)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/11/24 14:57
2	27614	(silicon near control\$3 near rectifier) SCR	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/11/24 14:58
3	378115	trigger\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/11/24 14:59
4	640	(ESD (electrostatic near discharge) ) and ((silicon near control\$3 near rectifier) SCR) and trigger\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/11/24 14:59
7	252	trigger-tap) (trigger\$3-tap) (trigger\$3 near3 tap	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/11/24 15:10
8	9	((ESD (electrostatic near discharge) ) and ((silicon near control\$3 near rectifier) SCR) and trigger\$3) and (trigger-tap) (trigger\$3-tap) (trigger\$3 near3 tap)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/11/24 15:10